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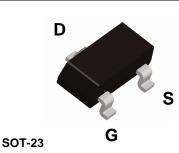
BSS138 N-Channel Logic Level Enhancement Mode Field Effect Transistor

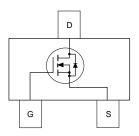
General Description

These N-Channel enhancement mode field effect transistors are produced using Fairchild's proprietary, high cell density, DMOS technology. These products have been designed to minimize on-state resistance while provide rugged, reliable, and fast switching performance. These products are particularly suited for low voltage, low current applications such as small servo motor control, power MOSFET gate drivers, and other switching applications.

Features

- + 0.22 A, 50 V. $R_{DS(ON)}$ = 3.5 Ω @ V_{GS} = 10 V $R_{DS(ON)}$ = 6.0 Ω @ V_{GS} = 4.5 V
- High density cell design for extremely low R_{DS(ON)}
- Rugged and Reliable
- Compact industry standard SOT-23 surface mount package





8mm

Absolute Maximum Ratings T_A=25°C unless otherwise noted

BSS138

Symbol		Parameter	Ratings	Units	
V _{DSS}	Drain-Source Voltage			50	V
V _{GSS}	Gate-Source	e Voltage	±20	V	
ID	Drain Currer	nt – Continuous	(Note 1)	0.22	А
		– Pulsed		0.88	
PD	Maximum P	ower Dissipation	(Note 1)	0.36	W
	Derate Abov	ve 25°C		2.8	mW/°C
T _J , T _{STG}	Operating an	nd Storage Junction Terr	-55 to +150	°C	
TL		ead Temperature for Sol /16" from Case for 10 Se	300	°C	
Therma	I Charact	eristics			
$R_{\theta JA}$	Thermal Res	350	°C/W		
Packag	e Marking	g and Ordering	Information		
Device Marking		Device	Reel Size	Tape width	Quantity

7"

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3000 units

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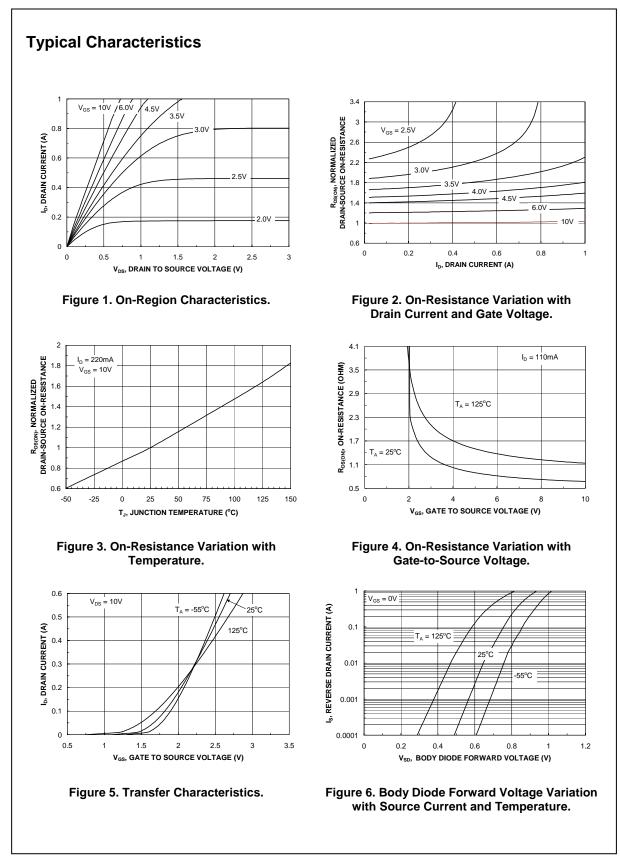
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics		1	1		
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = 250 \mu A$	50			V
<u>ΔBVdss</u> ΔTj	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}, \text{Referenced to } 25^{\circ}\text{C}$		72		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{\text{DS}} = 50 \text{ V}, \qquad V_{\text{GS}} = 0 \text{ V}$			0.5	μA
		$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V} \text{ T}_{J} = 125^{\circ}\text{C}$			5	μA
		$V_{\text{DS}} = 30 \text{ V}, \qquad V_{\text{GS}} = 0 \text{ V}$			100	nA
I _{GSS}	Gate-Body Leakage.	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, \qquad I_D = 1 \text{ mA}$	0.8	1.3	1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 1 \text{ mA,Referenced to } 25^{\circ}\text{C}$		-2		mV/∘C
R _{DS(on)}	Static Drain–Source	$V_{GS} = 10 \text{ V}, \qquad I_D = 0.22 \text{ A}$		0.7	3.5	Ω
	On-Resistance	$V_{GS} = 4.5 V, I_D = 0.22 A$		1.0	6.0	l
I _{D(on)}	On–State Drain Current	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 0.22 \text{ A}, \text{ T}_{J} = 125^{\circ}\text{C}$ $V_{GS} = 10 \text{ V}, V_{DS} = 5 \text{ V}$	0.2	1.1	5.8	А
g _{FS}	Forward Transconductance	$V_{DS} = 10V,$ $I_D = 0.22 \text{ A}$	0.12	0.5		S
•	Characteristics		01.12	0.0		
	Input Capacitance	$V_{DS} = 25 V$, $V_{GS} = 0 V$,		27		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		13		pF
C _{rss}	Reverse Transfer Capacitance			6		pF
R _G	Gate Resistance	$V_{GS} = 15 \text{ mV}, \text{ f} = 1.0 \text{ MHz}$		9		Ω
Switchin	g Characteristics (Note 2)	1				
t _{d(on)}	Turn–On Delay Time	$V_{DD} = 30 \text{ V}, \qquad I_D = 0.29 \text{ A},$		2.5	5	ns
t _r	Turn–On Rise Time	$V_{GS} = 10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		9	18	ns
t _{d(off)}	Turn–Off Delay Time			20	36	ns
t _f	Turn–Off Fall Time	1		7	14	ns
Q _q	Total Gate Charge	$V_{DS} = 25 V$, $I_D = 0.22 A$,		1.7	2.4	nC
Q _{qs}	Gate–Source Charge	$V_{GS} = 10 \text{ V}$		0.1		nC
Q _{gd}	Gate–Drain Charge			0.4		nC
0	ource Diode Characteristics	and Maximum Patings	1	1		
ls	Maximum Continuous Drain–Source				0.22	А
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = 0.44 A$ (Note 2)		0.8	1.4	V

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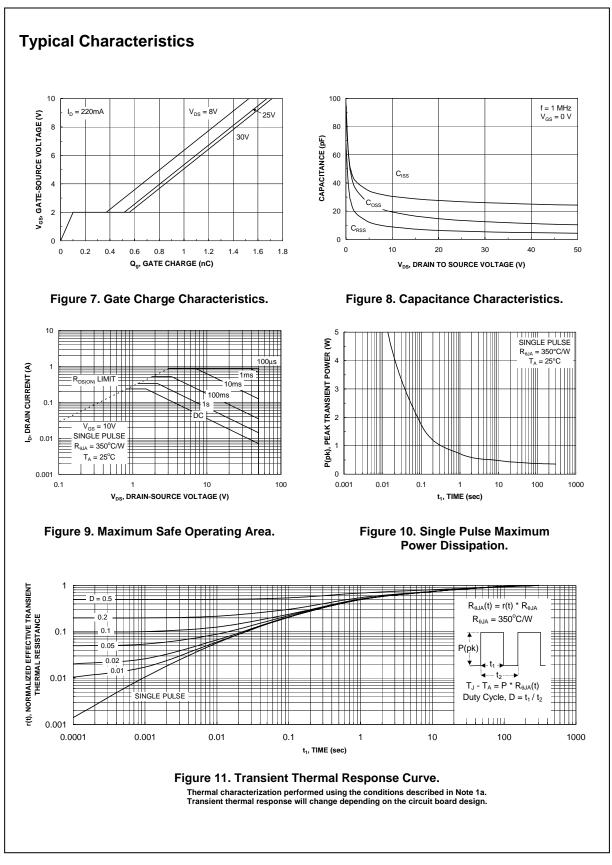
a) 350°C/W when mounted on a minimum pad..

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

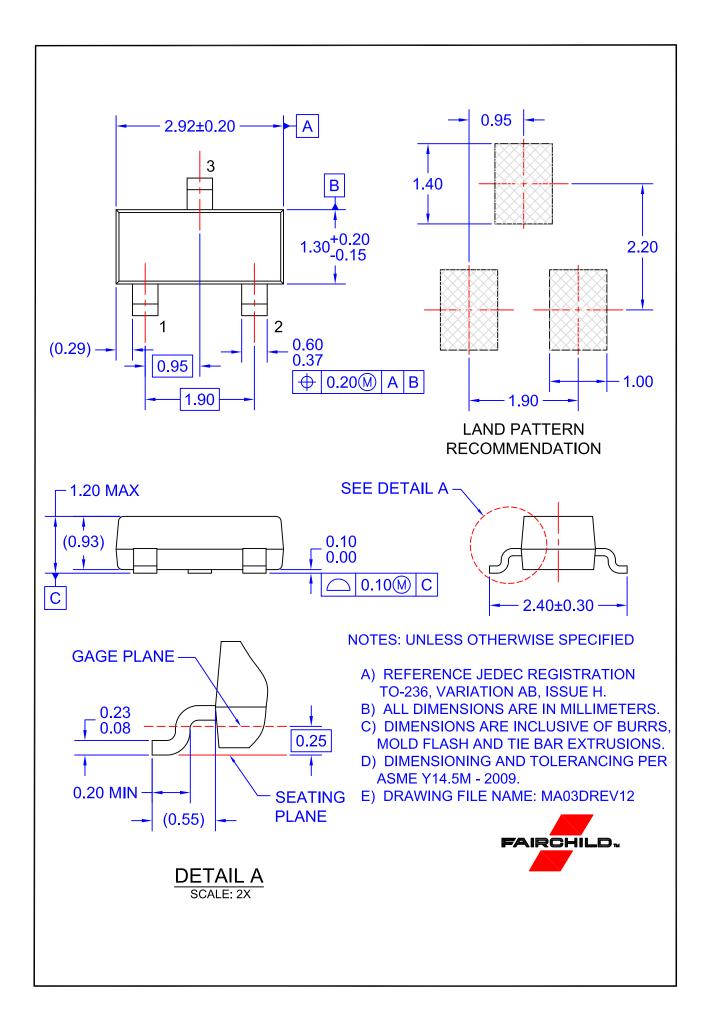


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